

Wideband

Low Noise Bypass Amplifier TSS-53LNB+

50Ω 0.5 to 5 GHz

The Big Deal

- Very wideband, 500 MHz – 5 GHz
- Ultra-flat gain, ± 0.7 dB from 700 to 2100 MHz
- Low NF over entire frequency band, 1.4 dB
- Internal bypass switching extends useable dynamic range



CASE STYLE: DQ1225

Product Overview

Mini-Circuits TSS-53LNB+ is a low-noise amplifier offering industry-leading performance over its full frequency range from 500 MHz to 5 GHz. It contains internal switching, allowing the user control of the amplifier to handle both high and low signal levels by bypassing the LNA in the presence of large signals. The TSS-53LNB+ utilizes E-PHEMT technology to achieve excellent noise figure performance in a unique cascade configuration enabling the combination of very wide band performance and flat gain. This model comes in a tiny, 3 x 3mm, 12-lead MCLP package.

Key Features

| Feature | Advantages |
|--|--|
| Ultra-wideband: 500 MHz – 5 GHz | Ideal for a wide range of receiver applications including military, commercial wireless, and instrumentation. |
| Very flat gain | Ideal for broadband or multi-band applications. Just one, cost-efficient model required for multiple frequency usage. |
| Minimal external matching components required. 15 dB return loss typ. | Minimizes the need for external matching networks, simplifying circuit designs, and enabling the amplifier to operate over multiple bands in a single application circuit. |
| High IP3: 48 dBm typ. (bypass mode) | Provides enhanced linearity over broad frequency range under high signal conditions. |
| Internal bypass switch feature | Unique design handles low to high signal levels with minimal noise distortion. |
| Built-in DC blocking cap at RF-Out port & separate pads for RF-Out & Vdd | Simplifies biasing eliminates need for Bias-Tee at output. |
| Compact size: 3 x 3 x 0.9 mm | Saves space in dense system layouts. Low inductance, repeatable transitions, and excellent thermal contact. |



Wideband

Low Noise Bypass Amplifier

0.5-5 GHz

Product Features

- Wideband: 0.5-5 GHz
- Built-in Bypass switching
- Low Noise figure: 1.4 dB typ. at 2.0 GHz
- High Gain: 21.7 dB typ. at 2 GHz
- Ultra Flat Gain: 0.7 dB from 0.7 to 2.1 GHz
- P1dB: +21 dBm typ. at 2.0 GHz
- Minimal matching components
- Specified over full band operation



TSS-53LNB+

CASE STYLE: DQ1225

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

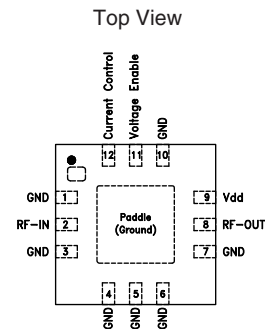
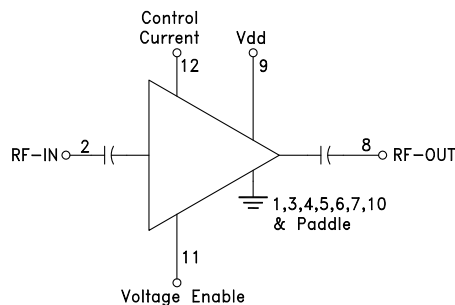
Typical Applications

- Wireless Base Station Systems
- Test and Measurement Systems
- Multi-Band Receivers

General Description

TSS-53LNB+ (RoHS compliant) is an advanced ultra-flat gain Low Noise wideband amplifier fabricated using E-PHEMT technology offering extremely high dynamic range over a broad frequency range. It has integrated switches enabling users to bypass the amplifier during high signal conditions. In addition, the TSS-53LNB+ has good input and output return loss over a broad frequency range without the need for external matching components. Lead finish is Sn-Ag alloy over Ni and is enclosed in a 12-lead MCLP package for good thermal performance.

simplified schematic and bonding pad description



| Function | Pad Number | Description (See Figure 2) |
|-----------------|-----------------------|---|
| RF-IN | 2 | RF-Input pad. Connect to Ground Via L1. Add a DC blocking cap in series of appropriate value if required. |
| RF-OUT | 8 | RF-Output pad. No external DC blocking cap required. |
| Current Control | 12 | Control Current pad, voltage level on this pad sets the I _{dd} . Connect to pad 11 via 3.92 kΩ resistor. |
| Voltage Enable | 11 | Voltage Enable Pad. Voltage level on this pad determines Amplifier is ON or bypassed. |
| Vdd | 9 | Supply Voltage Pad. Connect to Vdd via L2. |
| Ground | 1,3,4,5,6,7,10 Paddle | Connect to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance. |



Electrical Specifications⁽¹⁾ at 25°C, Zo=50Ω and v_{dd}=5V, unless otherwise noted

| Parameter | Condition (GHz) | Amplifier-ON | | | Amplifier-Bypass | Units |
|---|-----------------|--------------|-------|------|--------------------|-------|
| | | Min. | Typ. | Max. | Typ. | |
| Frequency Range | | 0.5 | | 5.0 | | GHz |
| Noise Figure | 0.5 | | 1.3 | | 0.7 | dB |
| | 1.0 | | 1.2 | | 0.9 | |
| | 2.0 | | 1.4 | | 0.9 | |
| | 3.0 | | 1.4 | | 1.0 | |
| | 4.0 | | 1.6 | | 1.4 | |
| Gain | 0.5 | — | 22.8 | — | -0.7 | dB |
| | 1.0 | — | 22.7 | — | -0.7 | |
| | 2.0 | 19.5 | 21.7 | 23.9 | -0.9 | |
| | 3.0 | — | 20.5 | — | -1.0 | |
| | 4.0 | — | 19.5 | — | -0.9 | |
| Gain Flatness | 0.7 - 2.1 | | ±0.7 | | ±0.14 | dB |
| | 0.5 | — | 16.0 | | 25.8 | |
| | 1.0 | — | 15.1 | | 18.5 | |
| | 2.0 | 10.5 | 14.5 | | 12.3 | |
| | 3.0 | — | 13.1 | | 11.1 | |
| Input Return Loss | 4.0 | — | 14.5 | | 14.5 | dB |
| | 5.0 | — | 16.9 | | 16.9 | |
| | 0.5 | | 11.8 | | 22.8 | |
| | 1.0 | | 12.5 | | 17.1 | |
| | 2.0 | | 17.0 | | 12.6 | |
| Output Return Loss | 3.0 | | 14.1 | | 11.7 | dB |
| | 4.0 | | 10.7 | | 14.0 | |
| | 5.0 | | 10.0 | | 11.9 | |
| | 0.5 | | 21.1 | | 32.0 | |
| | 1.0 | | 21.0 | | — | |
| Output Power @ 1dB compression AMP-ON ⁽²⁾ Input Power @ 1dB compression AMP-Bypass ⁽²⁾ | 2.0 | | 20.6 | | 33.0 | dBm |
| | 3.0 | | 20.1 | | — | |
| | 4.0 | | 20.2 | | — | |
| | 5.0 | | 19.2 | | 27.0 | |
| | 0.5 | | 35.1 | | 48.0 | |
| Output IP3 | 1.0 | | 34.5 | | 48.4 | dB |
| | 2.0 | | 33.9 | | 45.2 | |
| | 3.0 | | 32.7 | | 42.9 | |
| | 4.0 | | 33.4 | | 42.0 | |
| | 5.0 | | 30.9 | | 40.8 | |
| Device Operating Voltage (V _{dd}) | | 4.8 | 5.0 | 5.2 | 4.8-5.2 (5.0 typ.) | V |
| Device Operating Current (I _d) | | | 82 | 105 | 2 | mA |
| Enable Voltage (V _e) | | | 5.0 | | 0 | V |
| Enable Control Current (I _e) | | | 2.0 | | 0 | mA |
| DC Current (I _d) Variation Vs. Temperature ⁽³⁾ | | | -19 | | — | μA/°C |
| DC Current (I _d) Variation Vs. Voltage | | | 0.008 | | — | mA/mV |
| Thermal Resistance, junction-to-ground lead | | | 60 | | — | °C/W |

⁽¹⁾ Measured on Mini-Circuits Characterization test board TB-780+. See Characterization Test Circuit (Fig. 1)

⁽²⁾ Current increases at P1dB

⁽³⁾ (Current at 85°C - Current at -45°C)/130)

Absolute Maximum Ratings⁽⁵⁾

| Parameter | Ratings | |
|-------------------------------------|------------------|--|
| Operating Temperature (ground lead) | -40°C to 85°C | |
| Storage Temperature | -65°C to 150°C | |
| Total Power Dissipation | 0.7 W | |
| Input Power | Amplifier-ON | 8 dBm (continuous), 19 dBm (5 min max.) |
| | Amplifier Bypass | 16 dBm (continuous), 29 dBm (5 min max.) |
| DC Voltage V _{dd} | 7.0 V | |
| DC Voltage Enable | 7.0 V | |
| Max. Voltage on pad 8 | 15 V | |

⁽⁵⁾ Permanent damage may occur if any of these limits are exceeded.
Electrical maximum ratings are not intended for continuous normal operation.

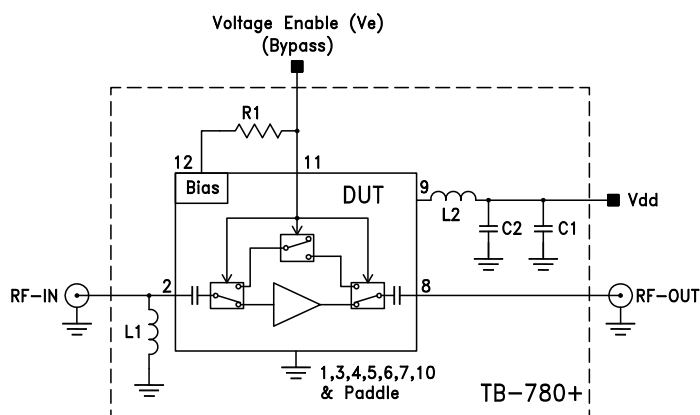
Enable Voltage (V_e) Fig. 1

| | Min. | Typ. | Max. | Units |
|------------------|------|------|------|-------|
| Amplifier-ON | 4.5 | 5.0 | 5.5 | V |
| Amplifier-Bypass | 0 | — | 0.5 | V |

Switching Specifications (Rise/Fall Time)

| Parameter | | Min. | Typ. | Max. | Units |
|-------------------------|----------------------------------|------|------|------|-------|
| Amplifier ON to Bypass | OFF TIME (50% Control to 10% RF) | — | 50 | — | ns |
| | FALL TIME (90 to 10% RF) | — | 12 | — | |
| Amplifier Bypass to ON | ON TIME (50% Control to 90% RF) | — | 740 | — | ns |
| | RISE TIME (10% to 90% RF) | — | 240 | — | |
| Control Voltage Leakage | | — | 65 | — | mV |

Characterization Test Circuit



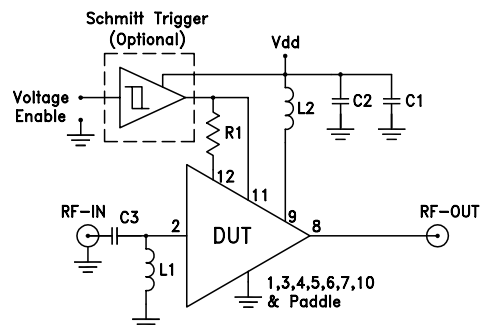
| Component | Size | Value | Units |
|-----------|------|-------|-------|
| L1 | 0402 | 47 | nH |
| L2 | 0402 | 56 | nH |
| C1 | 0402 | 0.1 | μF |
| C2 | 0402 | 10 | pF |
| R1 | 0402 | 3.92 | KΩ |

Fig 1. Block diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-780+) Gain, Return loss, Output power at 1dB compression (P1 dB) , output IP3 (OIP3) and noise figure measured using Agilent’s N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin=-25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
3. Switching Time: Pin=-25 dBm at 500 MHz. Venable=4.5, 5.0, 5.5V at 10 kHz. Vd=4.75, 5.0 and 5.5V.

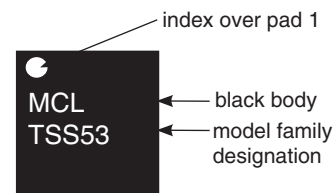
Recommended Application Circuit



| Component | Size | Value | Units |
|-----------------|--------------------------------------|-------|-------|
| L1 | 0402 | 47 | nH |
| L2 | 0402 | 56 | nH |
| R1 | 0402 | 3.92 | kΩ |
| C1 | 0402 | 0.1 | μF |
| C2 | 0402 | 10 | pF |
| C3 | 0402 | 1000 | pF |
| Schmitt Trigger | SN74LVC2G17DCKR Texas Instruments | | — |

Fig 2. Recommended Application Circuit.

Product Marking



| Additional Detailed Technical Information | |
|---|--|
| <i>additional information is available on our dash board. To access this information click here</i> | |
| Performance Data | Data Table |
| | Swept Graphs |
| | S-Parameter (S4P Files) Data Set (.zip file) |
| Case Style | DQ1225 <i>Plastic package, exposed paddle, terminal finish: tin-silver over nickel.</i> |
| Tape & Reel Standard quantities available on reel | F66 <i>7" reels with 20, 50, 100, 200, 500 or 1K devices.</i> |
| Suggested Layout for PCB Design | PL-421 |
| Evaluation Board | TB-779+ |
| Environmental Ratings | ENV12 |

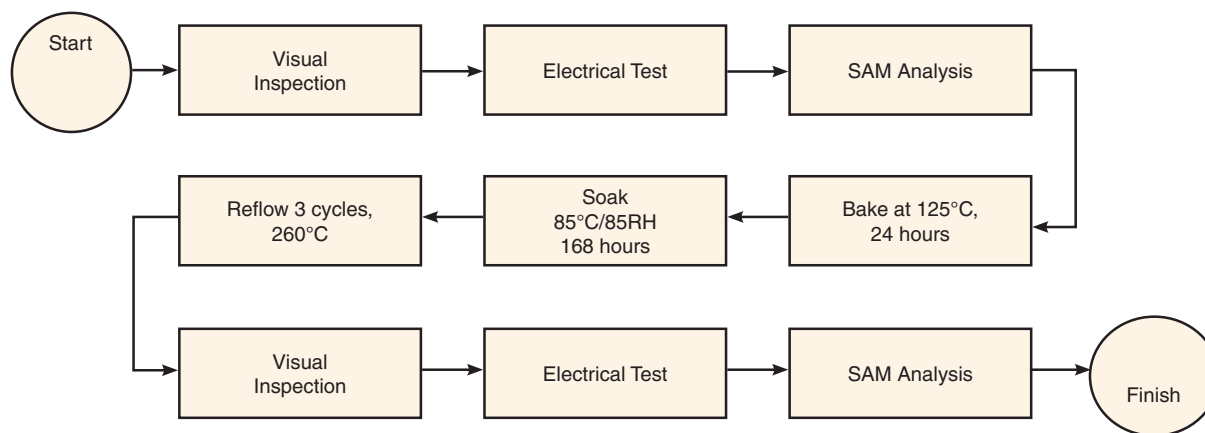
ESD Rating

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (pass 50V) in accordance with ANSI/ESD STM5.2-1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D



Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp